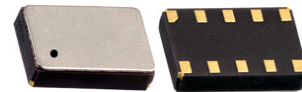


# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus



3.7 x 2.5 x 0.9 mm

AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant

Moisture Sensitivity Level: MSL=1

## FEATURES:

- With state-of-the-art RTC Technology by Micro Crystal AG
- RTC module with built-in “Tuning Fork” crystal oscillating at 32.768 kHz
- Factory calibrated, all built-in Temperature Compensation circuitry Time accuracy Option A & B. See Part Identification on page 7 for details
- Ultra low power consumption: 800nA typ @ VDD = 3.0V / Tamb = 25°C
- Wide clock operating voltage: 1.3 – 5.5V
- Wide interface operating voltage: 1.4 – 5.5V
- Extended operating temperature range: -40°C to +125°C
- SPI serial interface with fast mode SCL clock frequency of 1 MHz
- Provides year, month, day, weekday, hours, minutes and seconds
- Highly versatile alarm and timer functions
- Integrated Low-Voltage Detector, Power-On Reset and Self-Recovery System
- Main Power Supply to Backup Battery switchover circuitry with Trickle Charger
- Programmable CLKOUT pins for peripheral devices (32.768 kHz / 1024 Hz / 32 Hz / 1 Hz)
- Small and compact package size: 3.7 x 2.5 x 0.9 mm. RoHS-compliant and 100% leadfree

## APPLICATIONS:

- Wide range in communication & measuring equipment
- Commercial & Industrial applications
- Automotive electronics applications
- Wireless communications
- PDA and Palm Pilots
- Credit Cards with Security Technology

## STANDARD SPECIFICATIONS:

### Absolute Maximum Ratings

Parameters	Min.	Typ.	Max.	Units	Notes
Supply Voltage (V <sub>DD</sub> )	GND-0.3		+6.0	V	>GND / <V <sub>DD</sub>
Supply Current (I <sub>DD</sub> ; I <sub>SS</sub> )	-50		+50	mA	V <sub>DD</sub> Pin
Input Voltage (V <sub>I</sub> )	GND-0.3		V <sub>DD</sub> +0.3	V	Input Pin
Output Voltage (V <sub>O</sub> )	GND-0.5		V <sub>DD</sub> +0.5	V	$\overline{\text{INT}}$ / CLKOUT
DC Input Current (I <sub>I</sub> )	-10		+10	mA	
DC Output Current (I <sub>O</sub> )	-10		+10	mA	
Total Power Dissipation (P <sub>TOT</sub> )			300	mW	
Operating Temperature Range (T <sub>OPR</sub> )	-40		+125	°C	
Storage Temperature (T <sub>STO</sub> )	-55		+125	°C	Stored as bare product

### Frequency and Time Characteristics

V<sub>DD</sub>=3.0V; V<sub>SS</sub>=0V; T<sub>AMB</sub>=+25°C; f<sub>OSC</sub>=32.768kHz

Parameters	Min.	Typ.	Max.	Units	Notes
<b>32.768kHz Oscillator Characteristics</b>					
Frequency Accuracy ( $\Delta F/F$ )		±10	±20	ppm	F <sub>CLKOUT</sub> =32.768kHz; T <sub>AMB</sub> =+25°C; V <sub>DD</sub> =3.0V
Frequency vs Voltage ( $\Delta F/V$ )		±0.5	±1.0	ppm/V	T <sub>AMB</sub> =+25°C; V <sub>DD</sub> =1.4~5.5V
Frequency vs Temperature ( $\Delta F/T_{OPR}$ )	-0.035ppm/°C <sup>2</sup> (T <sub>OPR</sub> -T <sub>O</sub> ) <sup>2</sup> ±10%			ppm	T <sub>OPR</sub> =-40~+125°C; V <sub>DD</sub> =3.0V
Turnover Temperature (T <sub>O</sub> )	+20	+25	+30	°C	
Aging (first year)	-3		+3	ppm	T <sub>AMB</sub> =+25°C
Start-up Time Voltage (V <sub>START</sub> )					
Start-up Time (T <sub>START</sub> )		0.5	3	s	T <sub>AMB</sub> =-40 ~ +85°C
		1	3		T <sub>AMB</sub> =-40 ~ +125°C
CLKOUT duty cycle	40	50	60	%	F <sub>CLKOUT</sub> =32.768kHz; T <sub>AMB</sub> =+25°C

ABRACON IS  
ISO 9001 : 2008  
CERTIFIED



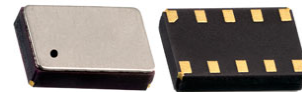
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Revised: 02.05.13

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# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus



3.7 x 2.5 x 0.9 mm

AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant

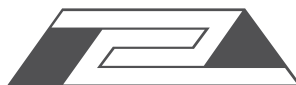
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Parameters		Min.	Typ.	Max.	Units	Notes
<b>Time accuracy, DTCXO Digitally Temperature Compensated</b>						
Time Accuracy Option: A ( $\Delta t/t$ )	$T_{AMB}=+25^{\circ}\text{C}$		$\pm 1$	$\pm 3$	ppm	
	$T_{AMB}=0 \sim +50^{\circ}\text{C}$		$\pm 2$	$\pm 4$		
	$T_{AMB}=-10 \sim +65^{\circ}\text{C}$		$\pm 3$	$\pm 5$		
	$T_{AMB}=-40 \sim +85^{\circ}\text{C}$		$\pm 4$	$\pm 6$		
	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$		$\pm 5$	$\pm 8$		
Time Accuracy Option: B ( $\Delta t/t$ )	$T_{AMB}=+25^{\circ}\text{C}$		$\pm 1$	$\pm 3$	ppm	
	$T_{AMB}=0 \sim +50^{\circ}\text{C}$		$\pm 3$	$\pm 5$		
	$T_{AMB}=-10 \sim +65^{\circ}\text{C}$		$\pm 5$	$\pm 10$		
	$T_{AMB}=-40 \sim +85^{\circ}\text{C}$		$\pm 10$	$\pm 25$		
	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$		$\pm 15$	$\pm 30$		

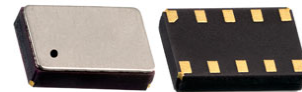
## Static Characteristics

$V_{DD}=1.4\sim 5.5\text{V}$ ;  $V_{SS}=0\text{V}$ ;  $T_{AMB}=-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$ ;  $f_{OSC}=32.768\text{kHz}$

Parameters		Min.	Typ.	Max.	Units	Notes
<b>Supplies</b>						
Supply Voltage ( $V_{DD}$ )		1.4		5.5	V	Time-keeping mode $I^2C$ bus reduced speed
		2.1		5.5		$I^2C$ bus full speed
Minimum Supply Voltage Detection ( $V_{LOW1}$ )		1.8		2.1	V	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$
Minimum Supply Voltage Detection ( $V_{LOW2}$ )		1.0		1.4	V	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$
Main Supply to Backup Supply Switchover Hysteresis ( $V_{HYST}$ )			20		mV	$V_{DD}$ to $V_{BACK} = 3.0\text{V}$
Supply Current $I_{DD}$ ( $V_{BACK}=0\text{V}$ ) or $I_{BACK}$ ( $V_{DD}=0\text{V}$ )	$V_{DD}=1.4\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$		0.6	1.5	$\mu\text{A}$	SPI bus inactive CLKOUT disabled $V_{BACK}=0\text{V}$ Or $V_{DD}=0\text{V}$
	$V_{DD}=1.4\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$			4.6		
	$V_{DD}=3.3\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$		0.8	2.0		
	$V_{DD}=3.3\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$			5.2		
	$V_{DD}=5.0\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$		0.9	2.2		
	$V_{DD}=5.0\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$			5.5		



# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus



AB-RTCMC-32.768kHz-EOA9-S3

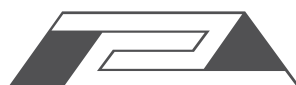


RoHS/RoHS II compliant

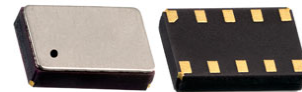
3.7 x 2.5 x 0.9 mm

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Parameters		Min.	Typ.	Max.	Units	Notes
Supply Current ( $I_{DD}$ )	SCL= 200kHz $V_{DD} = 1.4V$ $T_{AMB} = -40^{\circ}C \sim +85^{\circ}C$			14	$\mu A$	SPI bus active CLKOUT disabled
	SCL= 200kHz $V_{DD} = 1.4V$ $T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$			18		
	SCL= 1MHz $V_{DD} = 3.3V$ $T_{AMB} = -40^{\circ}C \sim +85^{\circ}C$			50		
	SCL= 1MHz $V_{DD} = 3.3V$ $T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$			55		
	SCL= 1MHz $V_{DD} = 5.0V$ $T_{AMB} = -40^{\circ}C \sim +85^{\circ}C$			65		
	SCL= 1MHz $V_{DD} = 5.0V$ $T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$			75		
Current Consumption ( $I_{DD32K}$ )	$V_{DD}=5.0V$		2.5	3.4	$\mu A$	SPI bus inactive CLKOUT =32.768kHz $C_{LOAD} =7.5pF$
	$V_{DD}=3.3V$		1.5	2.2		
	$V_{DD}=1.4V$		1.1	1.6		
<b>Input</b>						
LOW Level Input Voltage ( $V_{IL}$ )				$20\% * V_{DD}$	V	$V_{DD} = 1.4 \sim 5.5V_{DD}$ Pins:SCL,SDI,CLKOE,CE
HIGH Level Input Voltage ( $V_{IH}$ )		$80\% * V_{DD}$			V	
Input Leakage Current ( $I_L$ )	$T_{amb}=-40 \sim +85^{\circ}C$	-1		+1	$\mu A$	$V_{SS} > V_I < V_{DD}$
	$T_{amb}=-40 \sim +125^{\circ}C$	-1.5		+1.5		
Input Capacitance ( $C_I$ )				7	pF	



# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus



3.7 x 2.5 x 0.9 mm

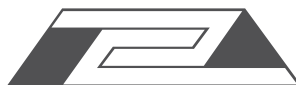
AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant

(Continued)

Parameters		Min.	Typ.	Max.	Units	Notes
<b>Output</b>						
HIGH Level Output Voltage ( $V_{OH}$ )	$V_{DD} = 1.4V; I_{OH} = 0.1mA$	1.0			V	
	$V_{DD} = 3.3V; I_{OH} = 1.5mA$	2.7				
	$V_{DD} = 5.0V; I_{OH} = 2.0mA$	4.5				
LOW Level Output Voltage ( $V_{OL}$ )	$V_{DD} = 1.4V; I_{OL} = 0.4mA$			0.2	V	
	$V_{DD} = 3.3V; I_{OL} = 1.5mA$			0.25		
	$V_{DD} = 5.0V; I_{OL} = 5.0mA$			0.8		
HIGH Level Output Current ( $I_{OH}$ )	$V_{OH} = 4.5V / V_{DD} = 5V$			2.0	mA	
LOW Level Output Current ( $I_{OL}$ )	$V_{OL} = 0.8V / V_{DD} = 5V$			-5.0	mA	
Output Leakage Current ( $I_{LO}$ )	$V_O = V_{DD} \text{ OR } V_{SS}$ $T_{AMB} = -40^{\circ}C \sim +85^{\circ}C$	-1	0	+1	$\mu A$	
	$V_O = V_{DD} \text{ OR } V_{SS}$ $T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$	-1.5	0	+1.5		
<b>Operating Temperature Range</b>						
Operating Temperature Range ( $T_{OPR}$ )		-40		+125	$^{\circ}C$	
<b>EEPROM Characteristics</b>						
Read Voltage ( $V_{Read}$ )	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$	1.4			V	
Programming Voltage ( $V_{Prog}$ )	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$	2.2			V	
EEPROM Programming Time ( $T_{Prog}$ )	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$ 1 Byte EEPROM User			35	ms	
	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$ 1 Byte EEPROM Control			100		
	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$ 2-4 Byte EEPROM Control			135		
EEPROM Write/Erase Cycles ( $V_{HYST}$ )	$V_{DD} \text{ to } V_{BACK} = 3.0V$	5000			Cycles	

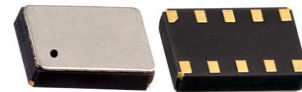


# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus

AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant



3.7 x 2.5 x 0.9 mm

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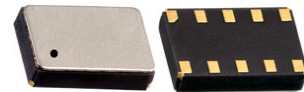
Parameters		Min.	Typ.	Max.	Units	Notes
<b>Trickle Charger</b>						
Current Limiting Resistors	R80K		80		kΩ	V <sub>DD</sub> = 5.0V V <sub>BACK</sub> = 3.0V T <sub>AMB</sub> = 25°C
	R20k		20			
	R5k		5			
	R1.5k		1.5			
<b>Thermometer</b>						
Thermometer Precision (T <sub>E</sub> )	T <sub>AMB</sub> = -40°C ~ +85°C		±4		°C	
	T <sub>AMB</sub> = -40°C ~ +125°C		±6			

## SPI Interface Dynamic Characteristics

V<sub>SS</sub>=0V; T<sub>AMB</sub>=-40°C ~+125°C; All timing values are valid within the operating supply voltage range and references to V<sub>IL</sub> and V<sub>IH</sub> with an input voltage swing from V<sub>SS</sub> and V<sub>DD</sub>.

Parameters	Symbol	Notes	V <sub>DD</sub> =1.6V		V <sub>DD</sub> =2.4V		V <sub>DD</sub> =3.3V		V <sub>DD</sub> =5.0V		Units
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
SCL Clock Frequency	f <sub>clk(SCL)</sub>			0.2		0.6		1.0		1.0	MHz
SCL Time	t <sub>SCL</sub>		5		1.7		1		1		μs
Clock HIGH Time	t <sub>clk(H)</sub>		1500		700		400		400		ns
Clock LOW Time	t <sub>clk(L)</sub>		1500		700		400		400		ns
Rise Time	t <sub>r</sub>	For SCL signal		800		800		200		200	ns
Fall Time	t <sub>f</sub>	For SCL signal		800		800		200		200	ns
CE Setup Time	t <sub>su(CE)</sub>		100		100		100		100		ns
CE Hold Time	t <sub>h(CE)</sub>		500		300		200		200		ns
CE Recovery Time	t <sub>rec(CE)</sub>		400		300		200		200		ns
CE Pulse Width	t <sub>w(CE)</sub>	Measured after valid subaddress is received		0.49		0.49		0.49		0.49	s
Setup Time	t <sub>su</sub>	Setup time for SDI data	20		20		20		20		ns
Hold Time	t <sub>h</sub>	Hold time for SDI data	500		300		200		200		ns
SDO Read Delay Time	t <sub>d(R)SDO</sub>	Bus load = 50pF		1300		650		350		350	ns
SDO Disable Time	t <sub>dis(SDO)</sub>	No load value; bus will be held up by bus-capacitance; use RC time constant with application values		200		100		50		50	ns
Transition Time SDI to SDO	t <sub>t(SDI-SDO)</sub>	Prepare for 0s to avoid bus conflict	0		0		0		0		ns





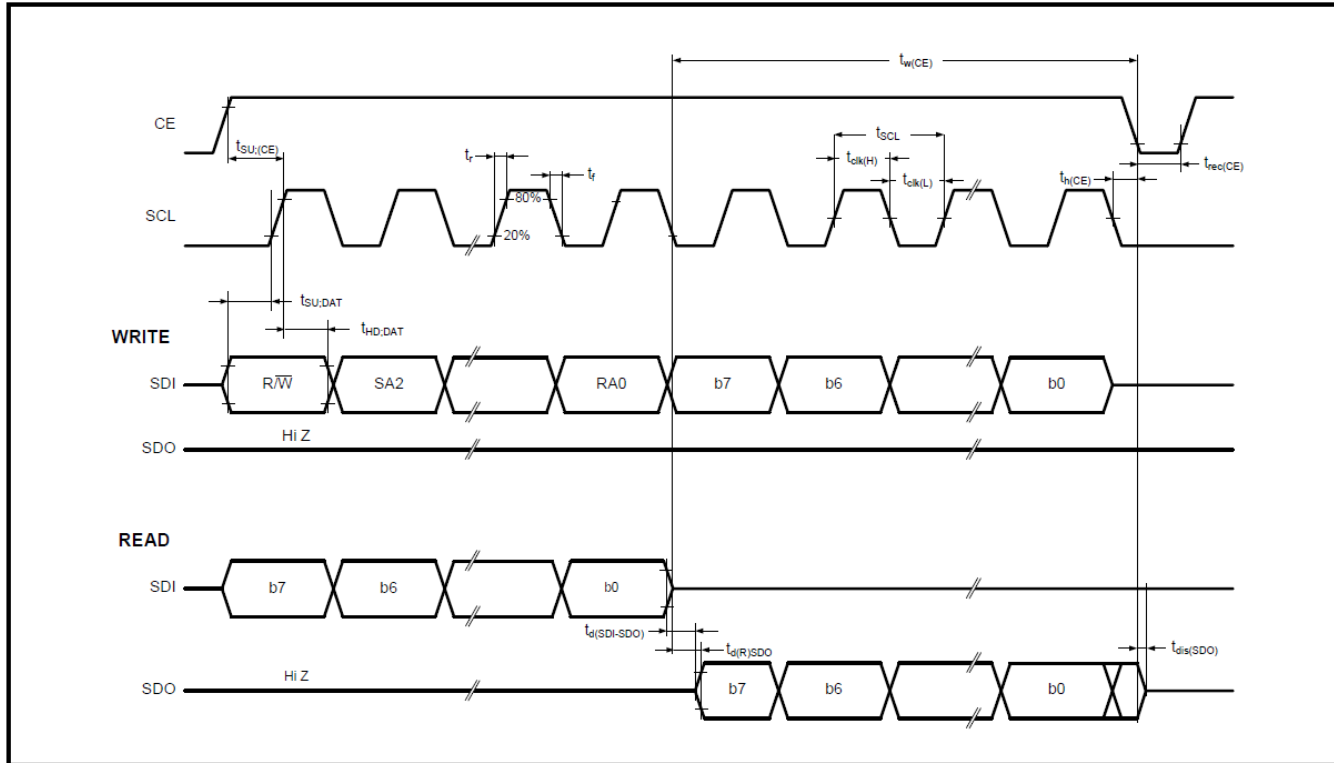
3.7 x 2.5 x 0.9 mm

AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant

## Interface Timing Characteristics



## PART IDENTIFICATION:

AB-RTCMC-32.768 kHz-EOA9-S3---

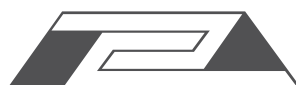
Operating Temp. Range
D: -40 ~ +85°C
H: -40 ~ +125°C

Timing Accuracy
A: see Table 1 below
B: see Table 1 below

Packaging
Blank: Bulk
T: 1000pcs/reel

Table 1. Time accuracy, DTCXO Digitally Temperature Compensated

Parameters		Min.	Typ.	Max.	Units
Time Accuracy Option: A	$T_{AMB}=+25^{\circ}\text{C}$		$\pm 1$	$\pm 3$	ppm
	$T_{AMB}=0 \sim +50^{\circ}\text{C}$		$\pm 2$	$\pm 4$	
	$T_{AMB}=-10 \sim +65^{\circ}\text{C}$		$\pm 3$	$\pm 5$	
	$T_{AMB}=-40 \sim +85^{\circ}\text{C}$		$\pm 4$	$\pm 6$	
	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$		$\pm 5$	$\pm 8$	
Time Accuracy Option: B	$T_{AMB}=+25^{\circ}\text{C}$		$\pm 1$	$\pm 3$	ppm
	$T_{AMB}=0 \sim +50^{\circ}\text{C}$		$\pm 3$	$\pm 5$	
	$T_{AMB}=-10 \sim +65^{\circ}\text{C}$		$\pm 5$	$\pm 10$	
	$T_{AMB}=-40 \sim +85^{\circ}\text{C}$		$\pm 10$	$\pm 25$	
	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$		$\pm 15$	$\pm 30$	











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- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

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